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Voltage Relationships of Carbon Nanotubes"; "3.3. Density Functional Theory for the Calculation of the ElectronDensitya?Potential Relationship in Carbon Nanotube Devices"; "3.4. DFTa?NEGF Simulations of Example Nanotubes"; "3.4.1. Simulations of Semiconductor Nanotubes"; "3.4.2. Simulations of Metallic Nanotubes"
"4. Carbon Nanotube Field Effect Transistors, Review of TheirEquivalent Circuit Models and Experimental Applications""5. Conclusion"; "References"; ""NANOWIRE FIELD-EFFECT TRANSISTORS"; "Abstract"; "1. Introduction"; "2. Brief Introduction to Nanowire Electronics"; "3. Typical 1-D Nanostructures"; "3.1. Nanorods"; "3.2. Nanowires"; "3.3. Nanotubes"; "3.4. Nanobelts"; "3.5. 1-D nanoscale Heterostructures"; "4. Application of Nanowire Transistors"; "4.1. Sensors"; "4.2. Light-Emitting Diodes and Nanolasers"; "4.3. Single Nanowire Solar Cells"
"4.4. Transparent Electronics""5. Conclusion", "Acknowledgments", "References", ""OPERATING CHARACTERISTICS OF MOSFETSIN CHAOTIC OSCILLATORS"; "Abstract", "Introduction", "Linear Operations", "Nonlinear Operators: PWL Functions", "Chaotic Oscillators Design: Chuaa?s Circuit", "Chaotic Synchronization and Encryption", "Conclusion", "Acknowledgments", "References", ""ONTHEVARIATIONALINEQUALITIESAPPROACHTOSTUDYELECTRICALCIRCUITSWITHTRANSISTORS"; "Abstract", "1.Introduction", "2.Set-valuedAmpere-VoltCharacteristics", "2.1.DiodeModels", "2.2.TransistorModels"
